

# 1 $\mu$ m-Band, High-Power Semiconductor Optical Amplifier

RA1060C, RA1030C



## Description

The RA1060C, RA1030C is a Semiconductor Optical Amplifier (SOA) designed for amplifying polarized optical signals in 1  $\mu$ m-band. It is also an ideal gain medium for implementing wide band-width tunable lasers. It shows Maximum performance together with ASE-Free light source,  $\lambda$ -Master 1040.

The semiconductor device is contained in a heat sink case, so it can be operated without TEC. The optical input/output are coupled to FC/APC connectors with fiber ports (PAF2A series, THORLABS) and uses PM980 fiber on both sides.

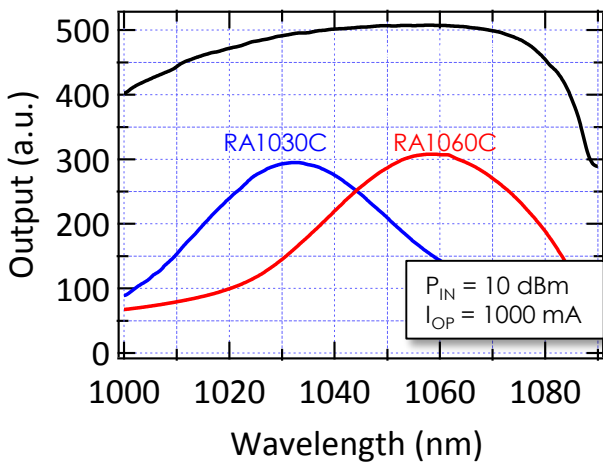
This device is designed to use LDC210C, THORLABS as a power supply.

## Specifications

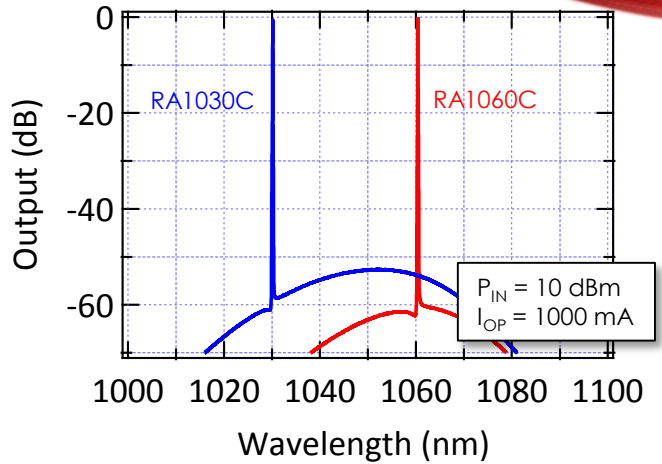
		Symbol	Min	Typ.	Max	Unit
Center Wavelength	RA1060C RA1030C	$\lambda_C$	1,055 1,030	1,060 1,035	1,065 1,040	nm
*980 nm is available						
Operating Current		$I_{OP}$	-	-	1,000	mA
Small Signal Gain @ $P_{IN} -20$ dBm		G	-	40	-	dB
Optical 3dB Bandwidth		BW	40	50	-	nm
Saturation PM-Fiber Output Power		$P_{SAT}$	22	23	-	dBm

# Performance Plots

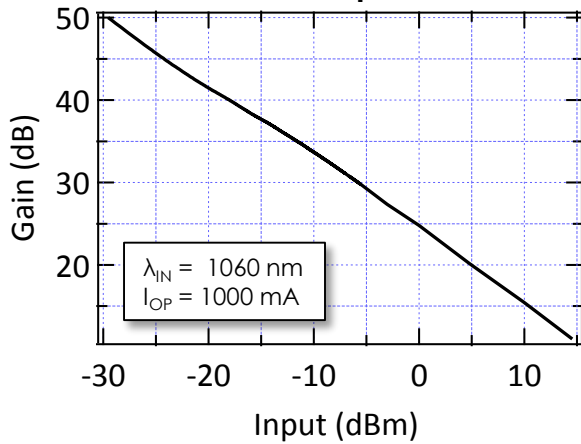
Output Power vs  $\lambda$  of Injection light



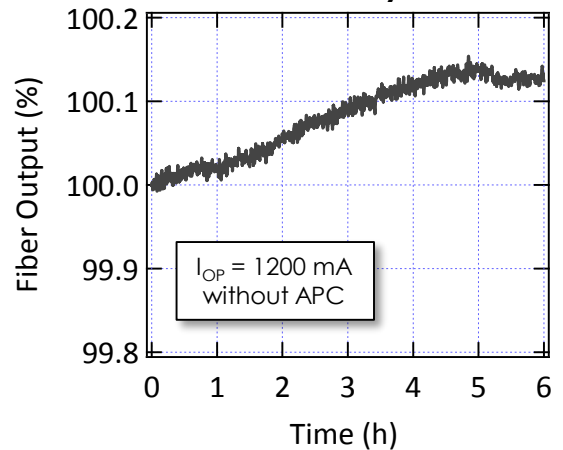
Spectra



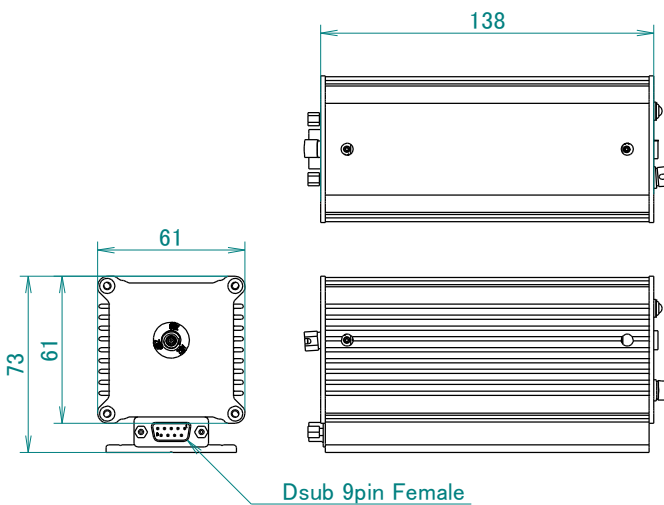
Gain vs Input Power



Stability



## Drawings



1. Interlock and status LASER ON/OFF
2. Photodiode cathode
3. Laser diode ground
4. Photodiode anode
5. Ground for pin 1
6. N.C.
7. Laser diode cathode
8. N.C.
9. N.C.

